



P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY

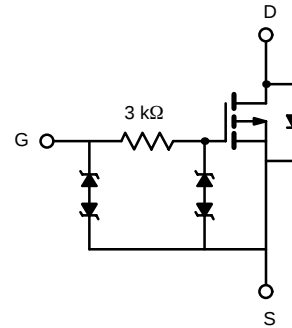
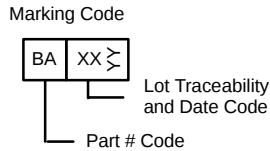
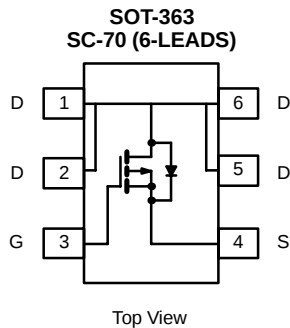
V_{DS} (V)	$r_{DS(on)}$ (Ω)	I_D (A)
-20	0.115 @ $V_{GS} = -4.5$ V	-2.9
	0.155 @ $V_{GS} = -2.5$ V	-2.4
	0.220 @ $V_{GS} = -1.8$ V	-2.0

FEATURES

- TrenchFET® Power MOSFETS: 1.8-V Rated
- ESD Protected: 3000 V
- Thermally Enhanced SC-70 Package

APPLICATIONS

- Load Switching
- PA Switch
- Level Switch

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter		Symbol	5 secs	Steady State	Unit
Drain-Source Voltage		V_{DS}	−20		V
Gate-Source Voltage		V_{GS}	± 12		
Continuous Drain Current ($T_J = 150^{\circ}\text{C}$) ^a	$T_A = 25^{\circ}\text{C}$	I_D	−2.9	−2.3	A
	$T_A = 85^{\circ}\text{C}$		−2.0	−1.6	
Pulsed Drain Current		I_{DM}	−8		
Continuous Diode Current (Diode Conduction) ^a		I_S	−1.4	−0.9	W
Maximum Power Dissipation ^a	$T_A = 25^{\circ}\text{C}$	P_D	1.56	1.0	
	$T_A = 85^{\circ}\text{C}$		0.81	0.52	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	−55 to 150		$^{\circ}\text{C}$

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	$t \leq 5$ sec	R_{thJA}	60	80	$^\circ\text{C/W}$
	Steady State		100	125	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	34	45	

Notes

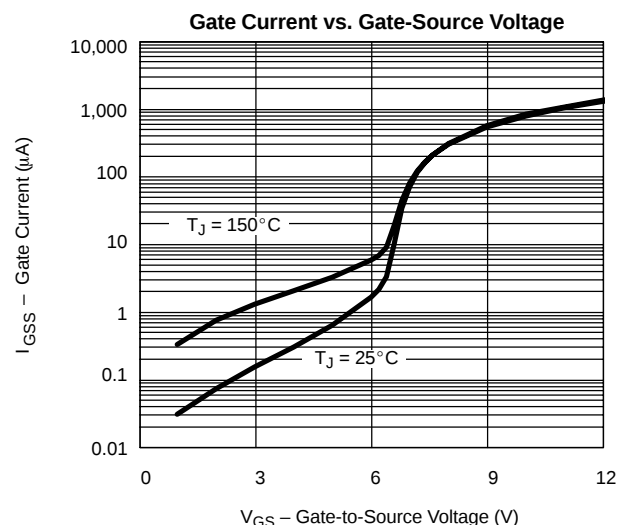
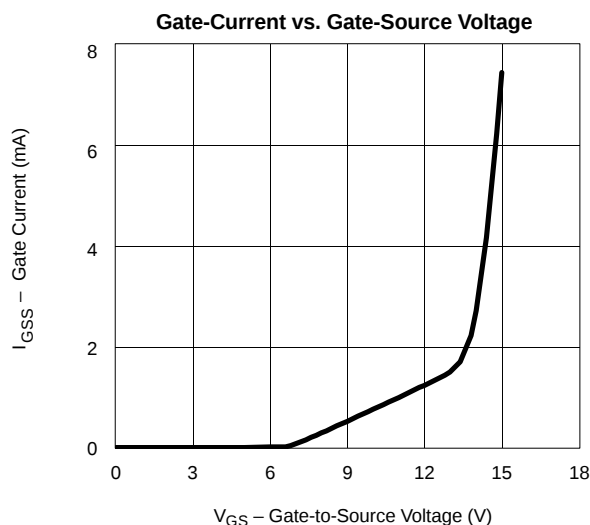
a. Surface Mounted on 1" x 1" FR4 Board.

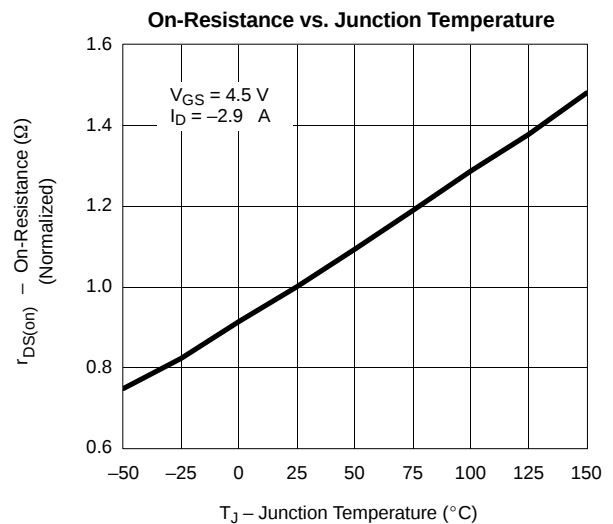
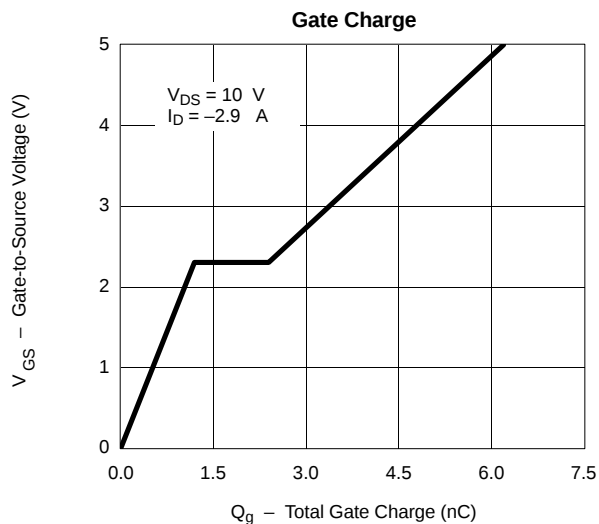
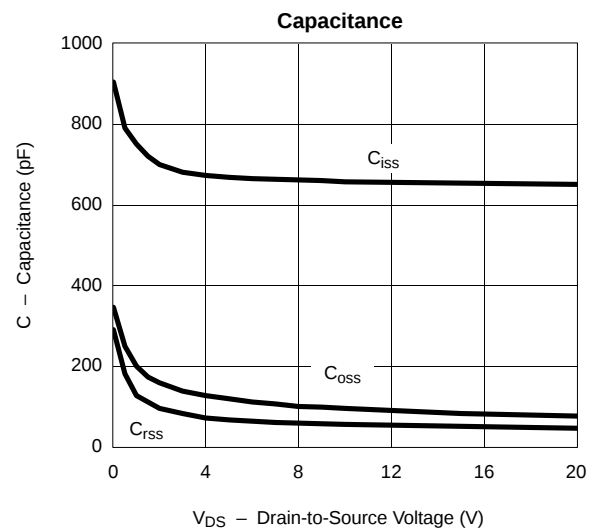
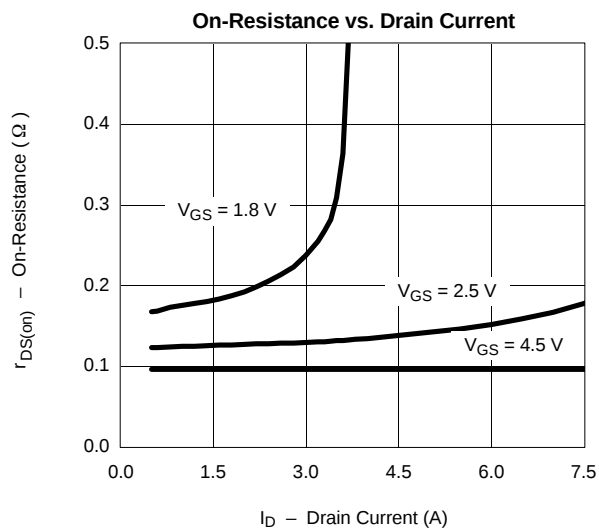
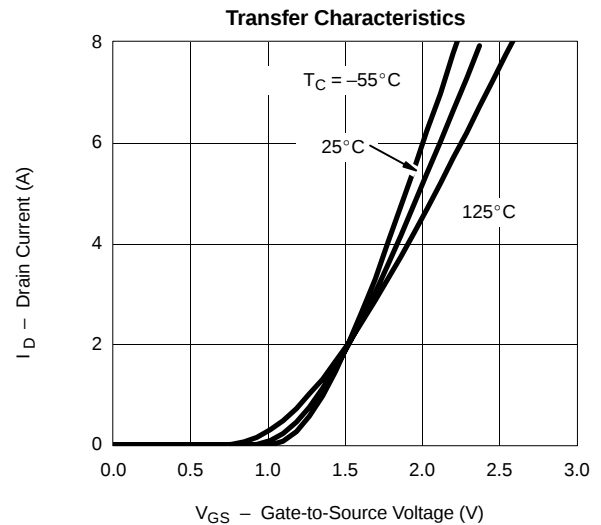
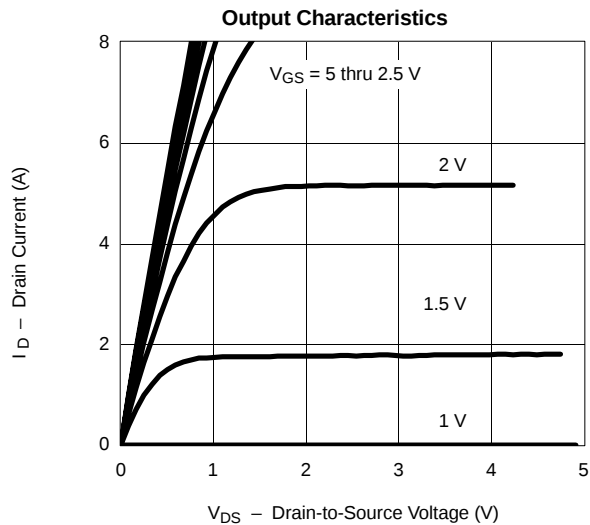
SPECIFICATIONS ($T_J = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

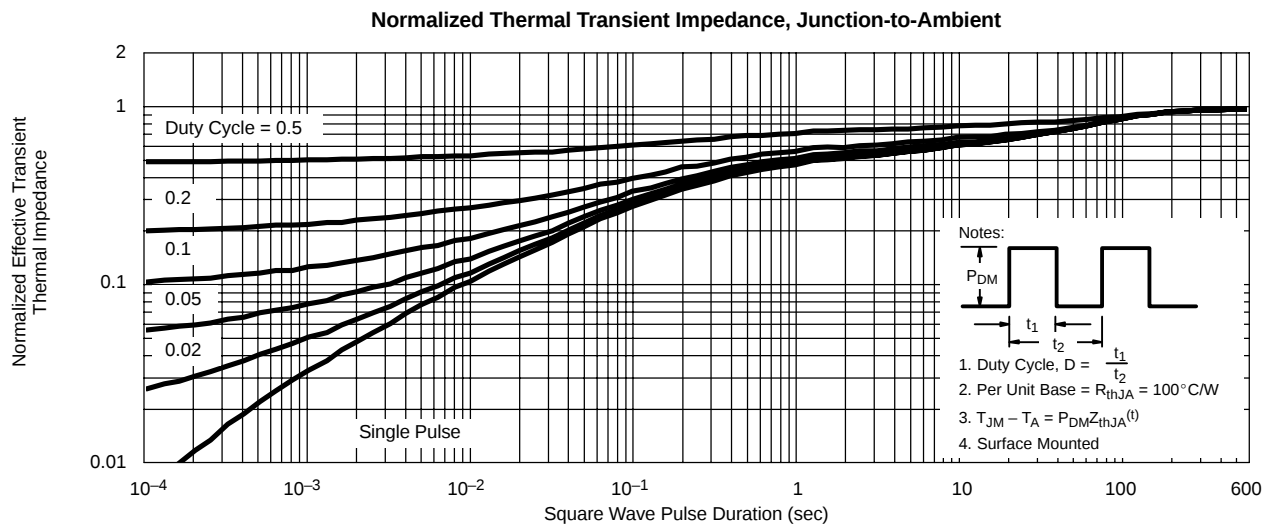
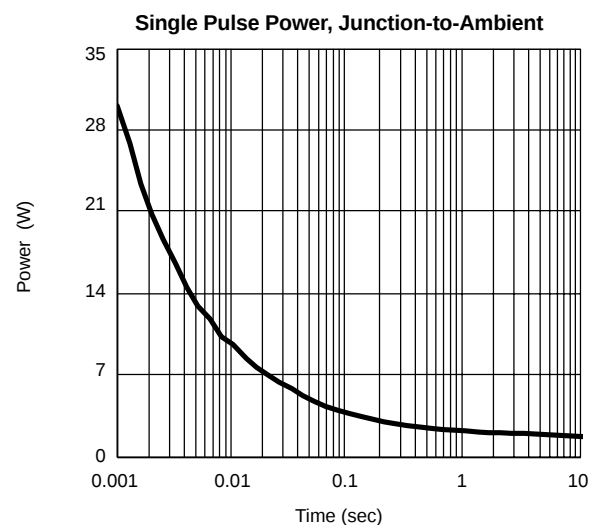
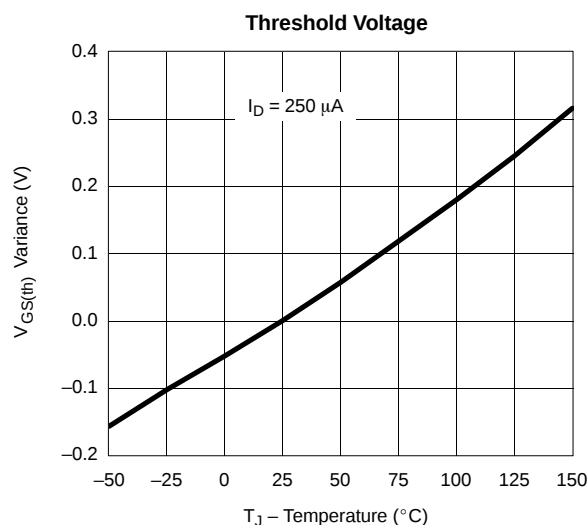
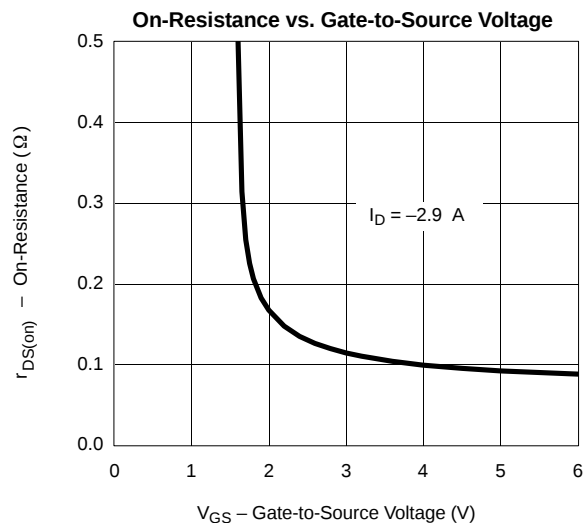
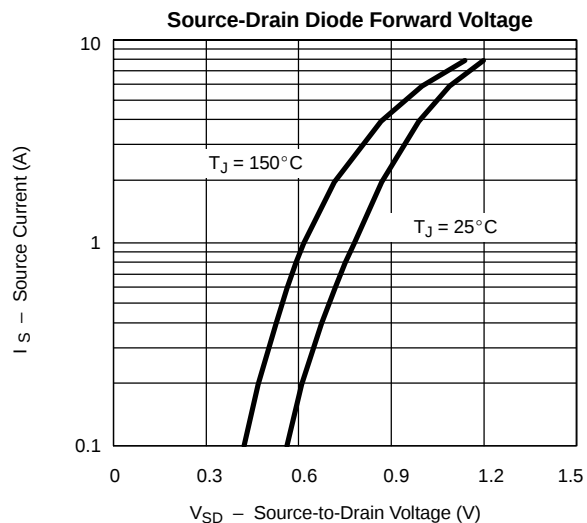
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Static						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -100\ \mu\text{A}$	-0.45			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0\ \text{V}$, $V_{GS} = \pm 4.5\ \text{V}$			± 1.5	μA
		$V_{DS} = 0\ \text{V}$, $V_{GS} = \pm 12\ \text{V}$			± 10	mA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -16\ \text{V}$, $V_{GS} = 0\ \text{V}$			-1	μA
		$V_{DS} = -16\ \text{V}$, $V_{GS} = 0\ \text{V}$, $T_J = 85^\circ\text{C}$			-5	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} = -5\ \text{V}$, $V_{GS} = -4.5\ \text{V}$	-4			A
Drain-Source On-State Resistance ^a	$r_{DS(on)}$	$V_{GS} = -4.5\ \text{V}$, $I_D = -2.9\ \text{A}$		0.095	0.115	Ω
		$V_{GS} = -2.5\ \text{V}$, $I_D = -2.4\ \text{A}$		0.125	0.155	
		$V_{GS} = -1.8\ \text{V}$, $I_D = -1.0\ \text{A}$		0.180	0.220	
Forward Transconductance ^a	g_{fs}	$V_{DS} = -10\ \text{V}$, $I_D = -2.9\ \text{A}$		6		S
Diode Forward Voltage ^a	V_{SD}	$I_S = -1.4\ \text{A}$, $V_{GS} = 0\ \text{V}$		-0.80	-1.1	V
Dynamic^b						
Total Gate Charge	Q_g	$V_{DS} = -10\ \text{V}$, $V_{GS} = -4.5\ \text{V}$, $I_D = -2.9\ \text{A}$		5.6	8	nC
Gate-Source Charge	Q_{gs}			1.2		
Gate-Drain Charge	Q_{gd}			1.2		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10\ \text{V}$, $R_L = 10\ \Omega$ $I_D \cong -1\ \text{A}$, $V_{GEN} = -4.5\ \text{V}$, $R_G = 6\ \Omega$		0.75	1.1	μs
Rise Time	t_r			1.6	2.3	
Turn-Off Delay Time	$t_{d(off)}$			3.9	5.5	
Fall Time	t_f			3.9	5.5	

Notes

- a. Pulse test; pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$.
b. Guaranteed by design, not subject to production testing.

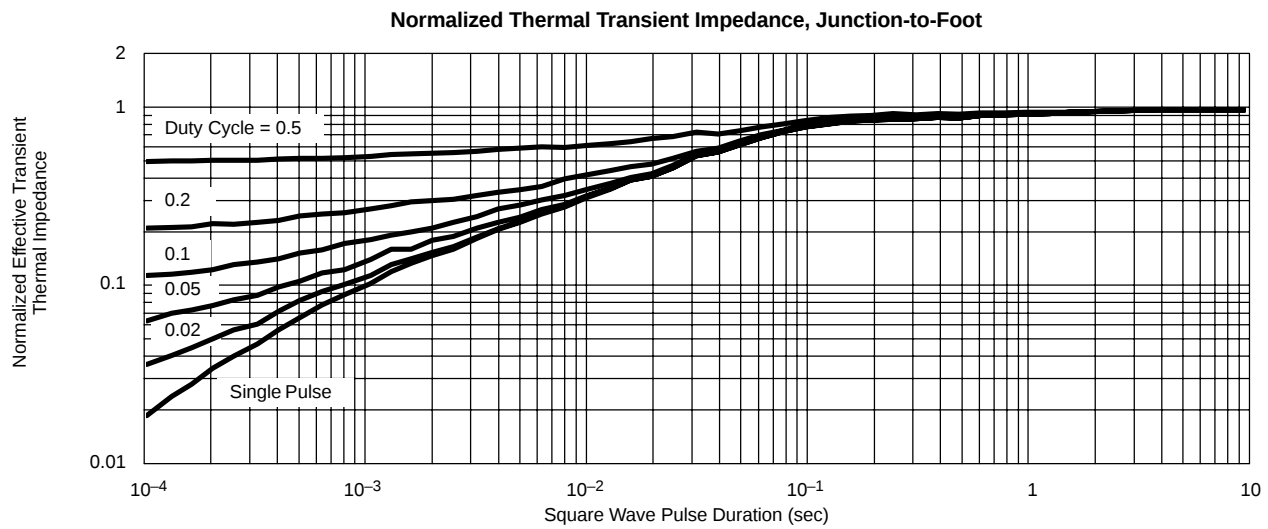
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

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